

6-Channel SD/ED/HD Video Filter with Charge Pump

ADA4424-6

FEATURES

3 SD channels; 18 MHz typical 1 dB bandwidth (BW) 3 ED/HD channels; 25 MHz or 34 MHz typical 1 dB BW Fixed gain of 6.2 dB (2.042 V/V)

On-board negative supply for output coupling without capacitors

Minimal dc offset at the output pins

Internal summation of Y and C channels for CVBS output Flexible input dc offset cancellation for luma channels D-terminal (EIAJ RC-5237 D5) and S-terminal (S1/S2) support Capable of driving 2 back-terminated 75 Ω video loads simultaneously

Separate power-down pins for SD and ED/HD sections 38-lead TSSOP package

Sony Green Partner Environmental Quality Approval Program compliant

APPLICATIONS

DVD players and recorders Set-top boxes Projectors Personal video recorders

GENERAL DESCRIPTION

The ADA4424-6 is a high performance video reconstruction filter specifically designed for consumer applications. It consists of a standard definition (SD) section with two fifth-order Butterworth filters and a high definition (HD) section with three fifth-order filters. The SD section contains an internal Y/C summer for CVBS output, whereas the HD section provides selectable corner frequencies for either extended definition (ED) or HD signals.

The ADA4424-6 filter/buffer section operates from a single 3.3 V supply. Full support for D-terminal (EIAJ RC-5237 D5) and S1/S2 signaling is provided, along with a dedicated 5 V supply pin. Separate enable pins are provided for the SD and HD sections.

FUNCTIONAL BLOCK DIAGRAM

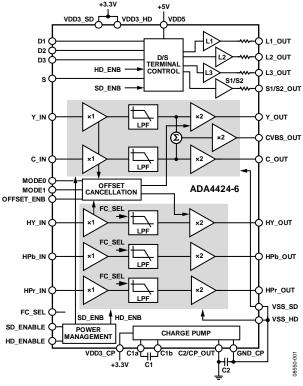


Figure 1.

The luma channels (Y_IN, HY_IN) of the ADA4424-6 are capable of detecting and cancelling dc input offsets of up to 1.1 V. Four distinct modes of detection/cancellation are available.

The output drivers on the ADA4424-6 feature rail-to-rail outputs with 6.2 dB gain. An on-board charge pump allows the outputs to swing up to 1.4 V below ground, eliminating the need for large coupling capacitors. Each output is capable of driving two 75 Ω doubly terminated cables.

The ADA4424-6 is available in a 38-lead TSSOP and operates in the industrial temperature range of -40°C to +85°C.

TABLE OF CONTENTS

10/09—Revision 0: Initial Version

reatures
Applications1
Functional Block Diagram
General Description1
Revision History
Specifications
Absolute Maximum Ratings
Thermal Resistance
Maximum Power Dissipation6
ESD Caution
Pin Configuration and Function Descriptions7
REVISION HISTORY
07/10—Rev. B to Rev. C
Change to General Description Section
05/10—Rev. A to Rev. B
Change to Table 1, Overall Performance
12/09—Rev. 0 to Rev. A
Changes to Table 1 4 Changes to Table 2 5 Changes to Table 5 10 Changes to Table 8 to Table 11 11
Change to Table 12 and Table 13

Typical Performance Characteristics	
Applications Information	
CVBS Output	
Corner Frequency Selection	
Input DC Offset Cancellation	
D-Terminal and S-Terminal Support	
Power-Down	
Charge Pump	
Printed Circuit Board (PCB) Layout	
Outline Dimensions	
Ordering Guide	

SPECIFICATIONS

 $V_{DD3} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$, $V_O = 2.042 \text{ V}$ p-p, $R_L = 150 \Omega$, dc-coupled outputs, unless otherwise noted. Charge pump configured as shown in Figure 18.

Table 1.

Parameter Test Conditions/Comments		Min	Тур	Max	Unit
OVERALL PERFORMANCE					
DC Voltage Gain	e Gain All channels		6.2	6.4	dB
Input Voltage Range, All Inputs	Not including dc offset		-0.6 to +1.4		V
Output Voltage Range, All Outputs			-1.6 to +3.0		V
Input Bias Current	Y_IN, HY_IN, dc-coupled		30		рА
Input Impedance	C_IN, HPb_IN, HPr_IN, ac-coupled		800		kΩ
Output Resistance	Y_OUT, C_OUT, CVBS_OUT, HY_OUT, HPb_OUT, HPr_OUT, dc-coupled		0.5		Ω
	L1_OUT, L2_OUT, L3_OUT, S1/S2_OUT, dc-coupled		10.5		kΩ
SD CHANNEL DYNAMIC PERFORMANCE					
In-Band Peaking	f = 100 kHz to 6.75 MHz		0.00	0.01	dB
1 dB Bandwidth		14	18		MHz
Out-of-Band Rejection	f = 148.5 MHz	38	42		dB
Crosstalk	f = 1 MHz		67		dB
Total Harmonic Distortion	$f = 1 \text{ MHz}, V_0 = 1.4 \text{ V p-p}$		0.07		%
Signal-to-Noise Ratio	f = 100 kHz to 6 MHz, unweighted		68		dB
Group Delay Variation	f = 100 kHz to 5 MHz		1		ns
Differential Gain	NTSC		0.2		%
Differential Phase	NTSC		0.5		Degrees
ED CHANNEL DYNAMIC PERFORMANCE	FC_SEL = low (0)				
In-Band Peaking	f = 100 kHz to 13.5 MHz		0.02	0.1	dB
1 dB Bandwidth	2		25		MHz
Out-of-Band Rejection	f = 148.5 MHz		42		dB
Crosstalk	f = 1 MHz		65		dB
Total Harmonic Distortion	$f = 5 \text{ MHz}, V_0 = 1.4 \text{ V p-p}$		0.45		%
Signal-to-Noise Ratio	f = 100 kHz to 13.5 MHz, unweighted		66		dB
Group Delay Variation	f = 100 kHz to 13.5 MHz		1.5		ns
HD CHANNEL DYNAMIC PERFORMANCE	FC_SEL = high (1)				
In-Band Peaking	f = 100 kHz to 30 MHz		0.1	0.2	dB
1 dB Bandwidth	Y Channel (HY_OUT)	30	39		MHz
	P Channels (HPb_OUT, HPr_OUT)	25	34		MHz
Out-of-Band Rejection	f = 148.5 MHz	33	37		dB
Crosstalk	f = 1 MHz		65		dB
Total Harmonic Distortion	$f = 10 \text{ MHz}, V_0 = 1.4 \text{ V p-p}$		1.2		%
Signal-to-Noise Ratio	f = 100 kHz to 30 MHz, unweighted		65		dB
Group Delay Variation	f = 100 kHz to 30 MHz		2.2		ns
DC CHARACTERISTICS					
Operating Voltage, 3.3 V Supply			3.14 to 3.46		V
Quiescent Supply Current, 3.3 V Supply	Both active, SD_ENABLE = high, HD_ENABLE = high, no load, no signal, not including D/S terminal outputs		93	133	mA
	SD disabled, SD_ENABLE = low, HD_ENABLE = high		54		mA
	HD disabled, SD_ENABLE = high, HD_ENABLE = low		45		mA
	Both disabled, SD_ENABLE = low, HD_ENABLE = low		6.1	10	mA
Operating Voltage, 5 V Supply	1011		4.75 to 5.25	-	V

arameter	Test Conditions/Comments	Min	Тур	Max	Unit
Quiescent Supply Current, 5 V Supply	SD_ENABLE = high, HD_ENABLE = high, $R_L = 100 \text{ k}\Omega$, D1, D2, D3 = high, S = high		190	200	μΑ
	SD_ENABLE = low, HD_ENABLE = low		5	15	μΑ
PSRR	ED/HD channels, output referred		-42		dB
	SD channels, output referred		-41		dB
DC Offset	See Table 6 and Table 7				
Input Referred, Offset Cancellation Disabled Mode	OFFSET_ENB = low				
SD Channels	$Y_IN = 0 V dc$	-60	-20	+60	m۷
CVBS Channel	$Y_IN = 0 V dc$	-100	-40	+100	mV
ED/HD Channels	$HY_IN = 0 V dc$	-60	-20	+60	m۷
Input Referred, Fixed Offset Cancellation Mode	OFFSET_ENB = high, MODE1 = high				
SD Fixed High Offset Mode	$Y_{IN} = 1.0 \text{ V dc}$, $MODE0 = low$	-100	-30	+100	mV
ED/HD Fixed High Offset Mode	$HY_IN = 1.1 V dc, MODE0 = low$	-100	-38	+100	mV
SD Fixed Low Offset Mode	Y_IN = 0.33 V dc, MODE0 = high	-90	-17	+90	mV
ED/HD Fixed Low Offset Mode	$HY_IN = 0.33 V dc, MODE0 = high$	-100	-25	+100	mV
Input Referred, Auto Offset Cancellation Mode	OFFSET_ENB = high, MODE1 = low				
SD Auto Offset Mode Sync Tip Sampling	Y_IN = 0 V to 1.0 V dc, MODE0 = low	-70	-36	+70	mV
ED/HD Auto Offset Mode Sync Tip Sampling	HY_IN = 0 V to 1.1 V dc, MODE0 = low	-95	-46	+95	mV
SD Auto Offset Mode Back Porch Sampling	Y_IN = 0 V to 1.0 V dc, MODE0 = high		-6	+25	mV
ED/HD Auto Offset Mode Back Porch Sampling	HY_IN = 0 V to 1.1 V dc, MODE0 = high	-25	-5	+25	mV
FC_SEL Input Logic Low Level		0		0.6	V
FC_SEL Input Logic High Level		1.2		V_{DD3}	V
xD_ENABLE, OFFSET_ENB, MODEx Input Logic Low Level		0		0.8	٧
xD_ENABLE, OFFSET_ENB, MODEx Input Logic High Level		2.0		V_{DD3}	٧
xD_ENABLE Assert Time	xD_ENABLE = low to high		95		ns
xD_ENABLE Deassert Time	xD_ENABLE = high to low		20		ns
xD_ENABLE Input Bias Current	Disabled, xD_ENABLE = low		6.1		μΑ
Input-to-Output Isolation	Disabled, xD_ENABLE = low, f = 5 MHz		-100		dB
D- and S-Terminal Input Logic Low Level	$R_L = 100 \text{ k}\Omega$	0		0.6	V
D- and S-Terminal Input Logic Mid Level	$R_L = 100 \text{ k}\Omega$	0.9		1.9	V
D- and S-Terminal Input Logic High Level	$R_L = 100 \text{ k}\Omega$	2.7		V_{DD3}	V
D- and S-Terminal Input Logic Open (Hi-Z) Resistance Value	$R_L = 100 \text{ k}\Omega$	200			kΩ
D-Terminal (L1_OUT, L2_OUT, L3_OUT) Low Level Output	$V_{DD5} = 5.0 \text{ V}, R_L = 100 \text{ k}\Omega, D1, D2, D3 = \text{low}$		0.0		V
D-Terminal (L1_OUT, L3_OUT) Mid Level Output	$V_{DD5} = 5.0 \text{ V}, R_L = 100 \text{ k}\Omega, D1, D3 = \text{mid or open}$		2.1		V
D-Terminal (L1_OUT, L2_OUT, L3_OUT) High Level Output	$V_{DDS} = 5.0 \text{ V}, R_L = 100 \text{ k}\Omega, D1, D2, D3 = \text{high}$		4.5		V
S-Terminal (S1/S2_OUT) Low Level Output	$V_{DDS} = 5.0 \text{ V, R}_L = 100 \text{ k}\Omega, S = \text{low}$		0.0		V

Parameter	Test Conditions/Comments	Min	Тур	Max	Unit
S-Terminal (S1/S2_OUT) Mid Level Output	$V_{DDS} = 5.0 \text{ V}, R_L = 100 \text{ k}\Omega, S = \text{mid or open}$		2.1		V
S-Terminal (S1/S2_OUT) High Level Output	$V_{DDS} = 5.0 \text{ V}, R_L = 100 \text{ k}\Omega, S = \text{high}$		4.5		V
CHARGE PUMP CHARACTERISTICS	All channels operating; C1 = C2 = 4.7 μ F, C3 = C4 = 1.0 μ F, R1 = 1 Ω (see Figure 18)				
Output Voltage			-1.66		V
Output Voltage Ripple			180		mV p-p
Output Ripple Frequency			100		kHz

ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
3.3 V Supply Voltage	3.6 V
5 V Supply Voltage	5.5 V
Digital Input Voltage (Pin 2 to Pin 5, Pin 8, Pin 12, Pin 15, Pin 16, Pin 23)	3.6 V
Power Dissipation	See Figure 2
Storage Temperature Range	−65°C to +125°C
Operating Temperature Range	-40°C to +85°C
Lead Temperature (Soldering, 10 sec)	300°C
Junction Temperature	150°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

 θ_{JA} is specified for the device soldered to a high thermal conductivity 4-layer (2s2p) circuit board, as described in EIA/JESD 51-7.

Table 3.

Package Type	θ _{JA}	Ө лс	Unit
38-Lead TSSOP	67.6	14.0	°C/W

MAXIMUM POWER DISSIPATION

The maximum safe power dissipation in the ADA4424-6 package is limited by the associated rise in junction temperature (T_I) on the die. At approximately 150°C, which is the glass transition temperature, the plastic changes its properties. Even temporarily exceeding this temperature limit can change the stresses that the package exerts on the die, permanently shifting the parametric performance of the ADA4424-6. Exceeding a junction temperature of 150°C for an extended time can result in changes in the silicon devices, potentially causing failure.

The power dissipated in the package (P_D) is the sum of the quiescent power dissipation and the power dissipated in the package due to the load drive for all outputs. The quiescent power is the voltage between the supply pins (V_S) times the quiescent current (I_S). The power dissipated due to load drive depends on the particular application. For each output, the power due to load drive is calculated by multiplying the load current by the associated voltage drop across the device. The power dissipated due to the loads is equal to the sum of the power dissipations due to each individual load. RMS voltages and currents must be used in these calculations.

Airflow increases heat dissipation, effectively reducing θ_{JA} . Figure 2 shows the maximum power dissipation in the package vs. the ambient temperature for the 38-lead TSSOP (67.6°C/W) on a JEDEC standard 4-layer board. θ_{JA} values are approximate.

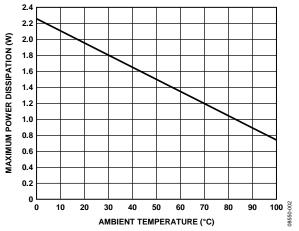


Figure 2. Maximum Power Dissipation vs. Ambient Temperature for a 4-Layer Board

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

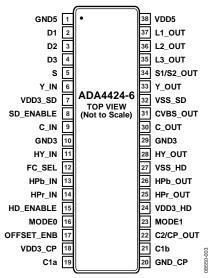


Figure 3. Pin Configuration, Top View

Table 4. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	GND5	Ground Pin for 5 V Supply.
2	D1	D-Terminal Vertical Resolution Selection Input.
3	D2	D-Terminal Scan Selection Input.
4	D3	D-Terminal Aspect Ratio Selection Input.
5	S	S-Terminal Aspect Ratio Selection Input.
6	Y_IN	SD Luma (Y) Input.
7	VDD3_SD	3.3 V Supply Pin for SD Filter Section.
8	SD_ENABLE	Output Enable Pin for SD (Y, C, CVBS).
9	C_IN	SD Chroma (C) Input.
10, 29	GND3	Ground Pins for 3.3 V Supply.
11	HY_IN	ED/HD Y Component Input.
12	FC_SEL	Filter Corner Frequency Selection Pin for HY, HPb, HPr Channels.
13	HPb_IN	ED/HD Pb Component Input.
14	HPr_IN	ED/HD Pr Component Input.
15	HD_ENABLE	Output Enable Pin for ED/HD (HY, HPb, HPr).
16	MODE0	This pin selects sync tip or back porch sampling when MODE1 = 0 and selects high or low fixed offset subtraction when MODE1 = 1.
17	OFFSET_ENB	Offset Cancellation Enable Pin.
18	VDD3_CP	3.3 V Supply Pins for Charge Pump Section.
19, 21	C1a, C1b	Charge Pump Capacitor C1 Connection Pin.
20	GND_CP	Ground Pin for 3.3 V Charge Pump Supply.
22	C2/CP_OUT	Charge Pump Output Pin. Connect Capacitor C2 from this pin to ground.
23	MODE1	Selects Automatic or Fixed Offset Subtraction Mode.
24	VDD3_HD	3.3 V Supply Pin for ED/HD Filter Section.
25	HPr_OUT	ED/HD Pr Component Output.
26	HPb_OUT	ED/HD Pb Component Output.
27	VSS_HD	Negative Supply Pin for ED/HD Filter Section. This pin should be connected to the charge pump output (Pin 22), as shown in Figure 18.
28	HY_OUT	ED/HD Y Component Output.
30	C_OUT	SD Chroma (C) Output.
31	CVBS_OUT	SD Composite Video (CVBS) Output.

Pin No.	Mnemonic	Description
32	VSS_SD	Negative Supply Pin for SD Filter Section. This pin should be connected to the charge pump output (Pin 22), as shown in Figure 18.
33	Y_OUT	SD Luma (Y) Output.
34	S1/S2_OUT	S-Terminal Aspect Ratio Selection Output.
35	L3_OUT	D-Terminal Aspect Ratio Selection Output.
36	L2_OUT	D-Terminal Scan Selection Output.
37	L1_OUT	D-Terminal Vertical Resolution Selection Output.
38	VDD5	5 V Supply Pin for D-Terminal and S-Terminal Signaling.

TYPICAL PERFORMANCE CHARACTERISTICS

 V_{DD3} = 3.3 V, T_A = 25°C, V_O = 2.042 V p-p, R_L = 150 Ω , dc-coupled outputs, unless otherwise noted. Charge pump configured as shown in Figure 18.

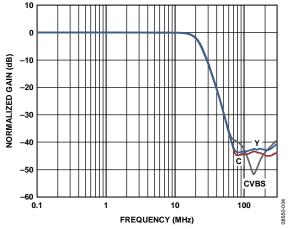


Figure 4. Frequency Response—SD Channels

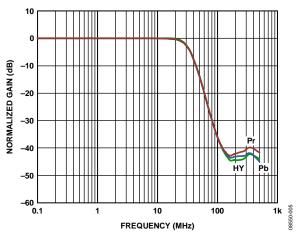


Figure 5. Frequency Response—ED Channels

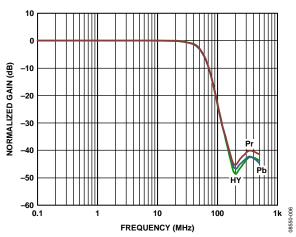


Figure 6. Frequency Response—HD Channels

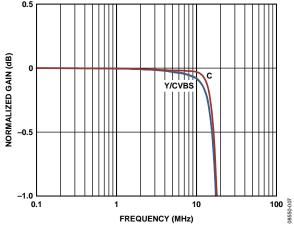


Figure 7. Frequency Response Peaking—SD Channels

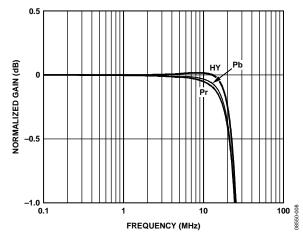


Figure 8. Frequency Response Peaking—ED Channels

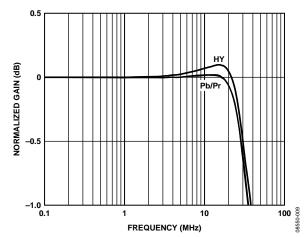


Figure 9. Frequency Response Peaking—HD Channels

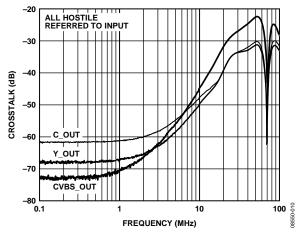


Figure 10. Crosstalk—SD Channels

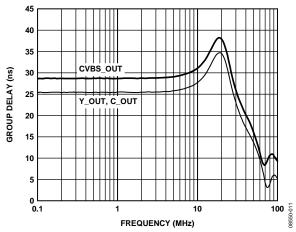


Figure 11. Group Delay—SD Channels

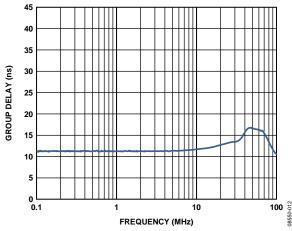


Figure 12. Group Delay—HD Channels

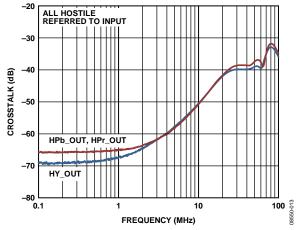


Figure 13. Crosstalk—ED and HD Channels

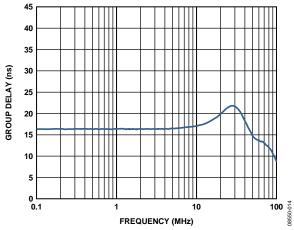


Figure 14. Group Delay—ED Channels

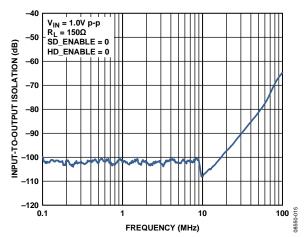


Figure 15. Input-to-Output Isolation—All Channels

APPLICATIONS INFORMATION CVBS OUTPUT

The composite video signal (CVBS_OUT) is produced by passively summing the Y and C channels (see Figure 1), after amplification by their respective gain stages. Each signal experiences a 6.2 dB loss from the passive summation and is subsequently amplified by 6.2 dB in the fixed stage following the summer. The net signal gain through the composite video path is, therefore, 0 dB, and the resulting composite signal present at the ADA4424-6 output is the sum of Y and C with unity gain.

CORNER FREQUENCY SELECTION

The component channels of the ADA4424-6 allow for a 1 dB filter corner frequency of either 25 MHz or 39 MHz/34 MHz. The FC_SEL pin operates as described in Table 5.

Table 5. ED/HD Bandwidth Selection

FC_SEL (Pin 12)	HD/ED	–1 dB Corner Frequency (Typ)
Low (0)	ED	25 MHz
High (1)	HD	39 MHz (HY); 34 MHz (Pb, Pr)

INPUT DC OFFSET CANCELLATION

The luma channels (Y_IN, HY_IN) of the ADA4424-6 are capable of detecting and cancelling dc input offsets of up to 1.1 V. Four distinct modes of detection/cancellation are available. These are selected via the MODE1 and MODE0 pins. The chroma (C_IN) and color difference (HPb_IN, HPr_IN) inputs do not support offset cancellation. It is recommended that these inputs be accoupled.

Automatic Detection/Cancellation Mode

There are two modes of automatic operation. The primary mode samples the input signal between the rising edge of the horizontal sync pulse and the start of active video (back porch), averages the value over the sampling interval, and subtracts it from the output signal. This is the more accurate method and is able to reduce the input-referred offsets to less than 25 mV.

An alternate method is available for copy-protected signals, where sampling the back porch may not provide a reliable dc average. This method detects the input negative sync tip, and clamps it to a fixed value (-214~mV for SD, and -300~mV for ED/HD). Sample intervals for SD and ED are shown in Figure 16, and the HD sample intervals are shown in Figure 17.

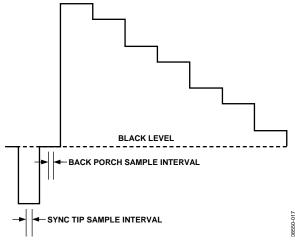


Figure 16. Back Porch and Sync Tip Sample Intervals (SD/ED)

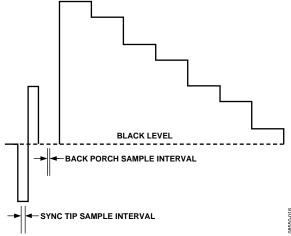


Figure 17. Back Porch and Sync Tip Sample Intervals (HD)

Fixed Offset Cancellation Mode

In addition to the automatic mode, there are two levels of fixed offset correction available. In high offset mode, fixed voltages of 1.0 V and 1.1 V are subtracted from the Y_IN and HY_IN inputs, respectively. In low offset mode, a fixed voltage of 0.33 V is subtracted from both Y_IN and HY_IN. The various modes of offset cancellation are outlined in Table 6.

Table 6. Offset Cancellation Mode Selection

MODE1 (Pin 23)	MODE0 (Pin 16)	Output Offset Cancellation
Low (0)	Low (0)	Auto-cancel, sync-tip sampling mode. Clamps the input referred SD sync tip to –214 mV, and the input referred ED/HD sync tip to –300 mV.
Low (0)	High (1)	Auto-cancel, back porch sampling mode. Sets the output blanking level to 0 V, independent of sync depth.
High (1)	Low (0)	Fixed cancellation mode, high dc offset.
		Subtracts 1.0 V from the Y_IN signal; subtracts 1.1 V from the HY_IN signal.
High (1)	High (1)	Fixed cancellation mode, low dc offset. Subtracts 0.33 V from both the Y_IN and HY_IN signals.

Offset Cancellation Disable

The offset cancellation function can be enabled or disabled via the OFFSET_ENB pin, as described in Table 7.

Table 7. Offset Cancellation Enable/Disable

OFFSET_ENB	
(Pin 17)	Offset Cancellation State
Low (0)	Offset cancellation is disabled.
High (1)	Offset cancellation is enabled. Function is determined by the MODE1 and MODE0 pins (see Table 6).

D-TERMINAL AND S-TERMINAL SUPPORT

Full D-terminal support (EIAJ RC-5237 D5) is provided for the component channels (HY_OUT, HPb_OUT, HPr_OUT). Level D1 through Level D5 are supported for vertical resolution, scan type, and aspect ratio selection. Details are shown in Table 8, Table 9, and Table 10.

S-terminal (also known as S_DC or S1/S2) support for S-video aspect ratio selection is also provided, as described in Table 11.

The VDD5 pin (Pin 38) provides 5 V power for these outputs. If D- or S-terminal support is not required, it is recommended that Pin 2 to Pin 5 and Pin 34 to Pin 38 remain unconnected.

Table 8. D-Terminal Control for Vertical Resolution Selection

Input Logic Level D1 (Pin 2)	Nominal Output (V) L1_OUT (Pin 37) $R_L = 100 \text{ k}\Omega$	Vertical Resolution (Number of Lines)
Low (0)	0.0	480
Mid or open	2.1	720
High (1)	4.5	1080

Table 9. D-Terminal Control for Scan Selection

Input Logic Level D2 (Pin 3)	Nominal Output (V) L2_OUT (Pin 36) $R_L = 100 \text{ k}\Omega$	Scan Type
Low (0)	0.0	Interlaced
Mid or open	2.1	N/A
High (1)	4.5	Progressive

Table 10. D-Terminal Control for Aspect Ratio Selection

Input Logic Level D3 (Pin 4)	Nominal Output (V) L3_OUT (Pin 35) $R_L = 100 \text{ k}\Omega$	Aspect Ratio
Low (0)	0.0	4:3
Mid or open	2.1	4:3 letterbox
High (1)	4.5	16:9

Table 11. S-Terminal Control for Aspect Ratio Selection

Input Logic Level S (Pin 5)	Nominal Output (V) $S1/S2_OUT$ (Pin 34) $R_L = 100 \text{ k}\Omega$	Aspect Ratio
Low (0)	0.0	4:3
Mid or open	2.1	4:3 letterbox
High (1)	4.5	16:9

POWER-DOWN

The ADA4424-6 provides separate output enable pins for the SD and ED/HD sections. In addition to powering down the Y, C, and CVBS outputs, the SD_ENABLE pin, when driven low, also places the S1/S2 output (S1/S2_OUT, Pin 34) in a high impedance state. Likewise, driving the HD_ENABLE pin low disables the component outputs (HY_OUT, HPb_OUT, and HPr_OUT) and changes the L1, L2, and L3 outputs (Lx_OUT, Pin 35 to Pin 37) to a high impedance state. Control details are shown in Table 12 and Table 13.

Table 12. Power-Down Control for SD Channels

SD_ENABLE (Pin 8)	SD Outputs (Y, C, CVBS)	S1/S2_OUT (Pin 34)
Low (0)	Disabled	High-Z (Open)
High (1)	Enabled	Active

Table 13. Power-Down Control for ED/HD Channels

HD_ENABLE (Pin 15)	ED/HD Outputs (HY, HPb, HPr)	Lx_OUT (Pin 35, Pin 36, Pin 37)
Low (0)	Disabled	High-Z (Open)
High (1)	Enabled	Active

CHARGE PUMP

The ADA4424-6 features an on-chip charge pump that supplies a negative rail voltage for the output stages. To minimize internal noise coupling, the charge pump uses an external connection to the negative supply pins (VSS_SD and VSS_HD). These pins should be connected to the C2/CP_OUT pin, each decoupled with a 1.0 μF capacitor. It is also recommended to place a small (1 Ω) series resistor in this connection. This forms a low-pass filter with the VSS decoupling capacitors and further reduces coupled noise. The charge pump also requires two 4.7 μF ceramic capacitors, one connected across the C1a and C1b pins, and one connected from the C2/CP_OUT pin to ground. The recommended charge pump configuration is shown in the application diagram (Figure 18).

With the black or zero level of the outputs placed at approximately ground potential, the outputs can swing up to 1.6 V in the negative direction. This eliminates the need for large output coupling capacitors because the input-referred dc offsets does not exceed $\pm 100~\rm mV$ (depending on the selected cancellation mode).

PRINTED CIRCUIT BOARD (PCB) LAYOUT

As with all high speed applications, attention to the PCB layout is of paramount importance. When designing with the ADA4424-6, adhere to standard high speed layout practices. A solid ground plane is recommended, and surface-mount, ceramic power supply decoupling capacitors should be placed as close as possible to the supply pins. Connect all of the ADA4424-6 GND pins to the ground plane with traces that are as short as possible. Controlled impedance traces of the shortest length possible should be used to connect to the signal I/O pins and should not pass over any voids in the ground plane. A 75 Ω impedance level is typically used in video applications. When driving transmission lines, include series termination resistors on the signal outputs of the ADA4424-6.

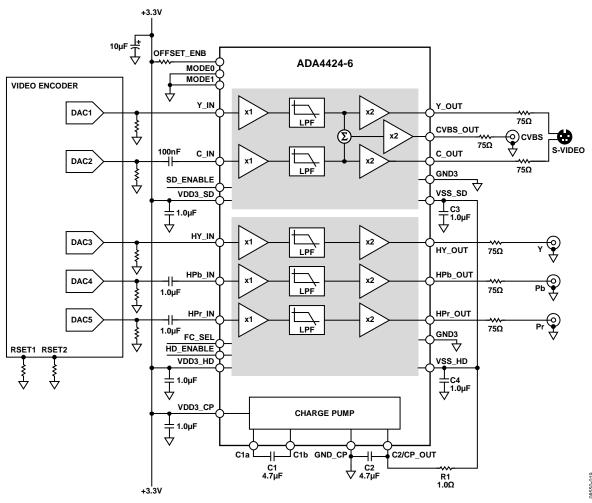


Figure 18. Typical Application Diagram for Using the ADA4424-6 in Auto Offset Cancellation Mode (D and S Terminal Connections Not Shown)

OUTLINE DIMENSIONS

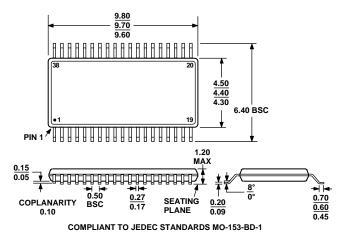


Figure 19. 38-Lead Thin Shrink Small Outline Package [TSSOP] (RU-38) Dimensions shown in millimeters

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option	Ordering Quantity
ADA4424-6ARUZ	-40°C to +85°C	38-Lead Thin Shrink Small Outline Package (TSSOP)	RU-38	50
ADA4424-6ARUZ-R7	-40°C to +85°C	38-Lead Thin Shrink Small Outline Package (TSSOP)	RU-38	1,000
ADA4424-6ARUZ-RL	-40°C to +85°C	38-Lead Thin Shrink Small Outline Package (TSSOP)	RU-38	2,500

 $^{^{1}}$ Z = RoHS Compliant Part.

ADA4424-6		
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NOTES



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

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- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
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- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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